Darlington 2SD2390



Silicon NPN Triple Diffused Planar Transistor (Complement to type 2SB1560)

Application: Audio, Series Regulator and General Purpose

■Absolute maximum ratings (Ta=25°C) Symbol Ratings Unit Vcbo 160 V VCEO 150 ٧ Vево 5 ٧ lс Α Ιв Α Рс 100(Tc=25°C) W Τj 150 °C

-55 to +150

Tstg

■Electrical Cl	naracteristics	(Ta	(Ta=25°C)		
Symbol	Conditions	Ratings	Unit		
Ісво	Vcb=160V	100max	μΑ		
І ЕВО	V _{EB} =5V	100max	μΑ		
V(BR)CEO	Ic=30mA	150min	V		
hfe	Vce=4V, Ic=7A	5000min*			
Vce(sat)	Ic=7A, IB=7mA	2.5max	V		
VBE(sat)	Ic=7A, IB=7mA	3.0max	V		
fr	Vce=12V, Ie=-2A	55typ	MHz		
Сов	VcB=10V, f=1MHz	95typ	pF		

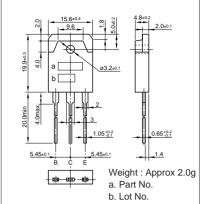
*hfe Rank \(\overline{O}(5000 to 12000), P(6500 to 20000), Y(15000 to 30000)

■Typical Switching Characteristics (Common Emitter)

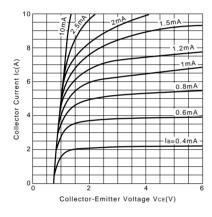
°C

71			,						
Vcc (V)	R _L (Ω)	Ic (A)	V _{BB1} (V)	V _{BB2} (V)	I _{B1} (mA)	I _{B2} (mA)	ton (µs)	tstg (µs)	tf (µs)
70	10	7	10	-5	7	-7	0.5tvp	10.0tvp	1.1typ

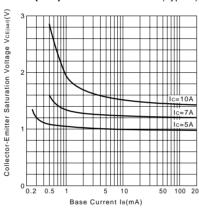
External Dimensions MT-100(TO3P)



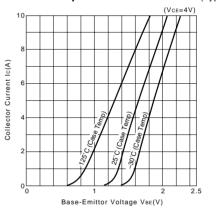
Ic-VcE Characteristics (Typical)



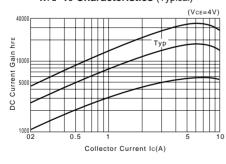
VcE(sat)-IB Characteristics (Typical)



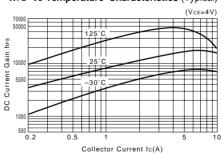
Ic-VBE Temperature Characteristics (Typical)



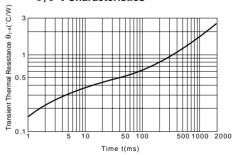
hfe-Ic Characteristics (Typical)



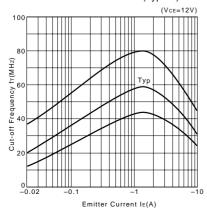
hfe-Ic Temperature Characteristics (Typical)



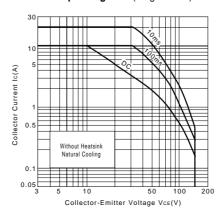
θ_{j-a}-t Characteristics



fT-IE Characteristics (Typical)



Safe Operating Area (Single Pulse)



Pc-Ta Derating

